ESP32-C6-WROOM-1 ESP32-C6-WROOM-1U

Datasheet

Module that supports 2.4 GHz Wi-Fi 6 (802.11 ax), Bluetooth® 5 (LE), Zigbee and Thread (802.15.4)

Built around ESP32-C6 series of SoCs, 32-bit RISC-V single-core microprocessor

Flash up to 16 MB

23 GPIOs, rich set of peripherals

On-board PCB antenna or external antenna connector



ESP32-C6-WROOM-1



ESP32-C6-WROOM-1U



1 Module Overview

Note:

Check the link or the QR code to make sure that you use the latest version of this document: https://espressif.com/documentation/esp32-c6-wroom-1-wroom-1u_datasheet_en.pdf



1.1 Features

CPU and On-Chip Memory

- ESP32-C6 embedded, 32-bit RISC-V single-core microprocessor, up to 160 MHz
- ROM: 320 KB
- HP SRAM: 512 KB
- LP SRAM: 16 KB

Wi-Fi

- 1T1R in 2.4 GHz band
- Operating frequency: 2412 ~ 2484 MHz
- IEEE 802.11ax-compliant
 - 20 MHz-only non-AP mode
 - MCS0 ~MCS9
 - Uplink and downlink OFDMA, especially suitable for simultaneous connections in high-density environments
 - Downlink MU-MIMO (multi-user, multiple input, multiple output) to increase network capacity
 - Beamformee that improves signal quality
 - Channel quality indication (CQI)
 - DCM (dual carrier modulation) to improve link robustness
 - Spatial reuse to maximize parallel transmissions
 - Target wake time (TWT) that optimizes power saving mechanisms
- Fully compatible with IEEE 802.11b/g/n protocol

- 20 MHz and 40 MHz bandwidth
- Data rate up to 150 Mbps
- Wi-Fi Multimedia (WMM)
- TX/RX A-MPDU, TX/RX A-MSDU
- Immediate Block ACK
- Fragmentation and defragmentation
- Transmit opportunity (TXOP)
- Automatic Beacon monitoring (hardware TSF)
- 4 × virtual Wi-Fi interfaces
- Simultaneous support for Infrastructure BSS in Station mode, SoftAP mode, Station + SoftAP mode, and promiscuous mode Note that when ESP32-C6 scans in Station mode, the SoftAP channel will change along with the Station channel
- 802.11mc FTM

Bluetooth

- Bluetooth LE: Bluetooth 5.3 certified
- Bluetooth mesh
- High power mode (20 dBm)
- Speed: 125 Kbps, 500 Kbps, 1 Mbps, 2 Mbps
- Advertising extensions
- Multiple advertisement sets
- Channel selection algorithm #2
- LE power control

 Internal co-existence mechanism between Wi-Fi and Bluetooth to share the same antenna

IEEE 802.15.4

- Compliant with IEEE 802.15.4-2015 protocol
- OQPSK PHY in 2.4 GHz band
- Data rate: 250 Kbps
- Thread 1.3
- Zigbee 3.0

Peripherals

• GPIO, SPI, parallel IO interface, UART, I2C, I2S, RMT (TX/RX), pulse counter, LED PWM, USB Serial/JTAG controller, MCPWM, SDIO2.0 slave controller, GDMA, TWAI® controller, on-chip debug functionality via JTAG, event task matrix, ADC, temperature sensor, general-purpose timers, watchdog timers, etc.

Note:

* Please refer to ESP32-C6 Series Datasheet for detailed information about the module peripherals.

Integrated Components on Module

- 40 MHz crystal oscillator
- SPI flash

Antenna Options

- On-board PCB antenna (ESP32-C6-WROOM-1)
- External antenna via a connector (ESP32-C6-WROOM-1U)

Operating Conditions

- Operating voltage/Power supply: 3.0 ~ 3.6 V
- Operating ambient temperature:
 - 85 °C version module: -40 ~ 85 °C
 - 105 °C version module: -40 ~ 105 °C

1.2 **Description**

ESP32-C6-WROOM-1 and ESP32-C6-WROOM-1U are two powerful, general-purpose Wi-Fi, IEEE 802.15.4, and Bluetooth LE modules. The rich set of peripherals and high performance make the module an ideal choice for smart homes, industrial automation, health care, consumer electronics, etc.

ESP32-C6-WROOM-1 comes with a PCB antenna. ESP32-C6-WROOM-1U comes with a connector for an external antenna. They both feature an external SPI flash up to 16 MB.

Both ESP32-C6-WROOM-1 and ESP32-C6-WROOM-1U come in two versions:

- 85 °C version
- 105 °C version

The two versions only vary in maximum ambient temperature and flash part number. In this datasheet unless otherwise stated, ESP32-C6-WROOM-1 refers to the ESP32-C6-WROOM-1 module in 85 °C and 105 °C versions, and ESP32-C6-WROOM-1U refers to the ESP32-C6-WROOM-1U module in 85 °C and 105 °C versions.

The series comparison for the two modules is as follows:

Table 1: ESP32-C6-WROOM-1 (ANT) Series Comparison¹

Ordering Code	Flash	Ambient Temp. ¹ (°C)	Size ² (mm)	
ESP32-C6-WROOM-1-N4	4 MB (Quad SPI)	− 40 ~ 85		
ESP32-C6-WROOM-1-H4	4 IVID (Quad SPI)	− 40 ~ 105	18.0 × 25.5 × 3.2	
ESP32-C6-WROOM-1-N8	8 MB (Quad SPI)	-40 ∼ 85	10.0 x 20.0 x 3.2	
ESP32-C6-WROOM-1-N16	16 MB (Quad SPI)			

¹ This table shares the same notes presented in Table 2 below.

Table 2: ESP32-C6-WROOM-1U (CONN) Series Comparison

Ordering Code	Flash	Ambient Temp. ¹ (°C)	Size ² (mm)	
ESP32-C6-WROOM-1U-N4	4 MB (Quad SPI)	− 40 ~ 85		
ESP32-C6-WROOM-1U-H4	4 IVID (Quad SFI)	− 40 ~ 105	18.0 × 19.2 × 3.2	
ESP32-C6-WROOM-1U-N8	8 MB (Quad SPI)	-40 ∼ 85	10.0 x 19.2 x 3.2	
ESP32-C6-WROOM-1U-N16	16 MB (Quad SPI)	<u> </u>		

¹ Ambient temperature specifies the recommended temperature range of the environment immediately outside the Espressif module.

At the core of the modules is ESP32-C6, a 32-bit RISC-V single-core processor.

ESP32-C6 integrates a rich set of peripherals including SPI, parallel IO interface, UART, I2C, I2S, RMT (TX/RX), LED PWM, USB Serial/JTAG controller, MCPWM, SDIO2.0 slave controller, GDMA, TWAI[®] controller, on-chip debug functionality via JTAG, event task matrix, as well as up to 23 GPIOs, etc.

Note:

1.3 Applications

- Smart Home
- Industrial Automation
- Health Care
- Consumer Electronics
- Smart Agriculture

- POS machines
- Service robot
- Audio Devices
- Generic Low-power IoT Sensor Hubs
- Generic Low-power IoT Data Loggers

² For details, refer to Section 8.1 *Physical Dimensions*.

^{*} For more information on ESP32-C6, please refer to ESP32-C6 Series Datasheet.

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Block Diagram 2

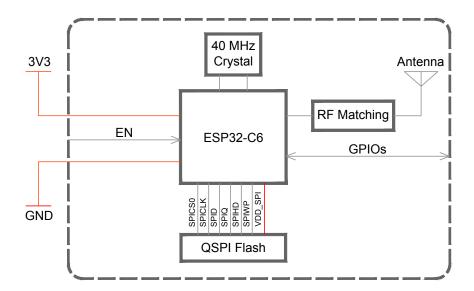


Figure 1: ESP32-C6-WROOM-1 Block Diagram

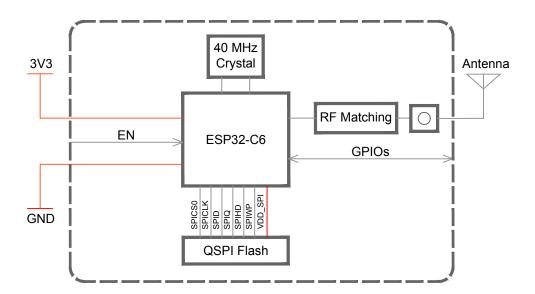


Figure 2: ESP32-C6-WROOM-1U Block Diagram

3 Pin Definitions

3.1 Pin Layout

The pin diagram below shows the approximate location of pins on the module. For the actual diagram drawn to scale, please refer to Figure 8.1 *Physical Dimensions*.

The pin diagram is applicable for ESP32-C6-WROOM-1 and ESP32-C6-WROOM-1U, but the latter has no keepout zone.

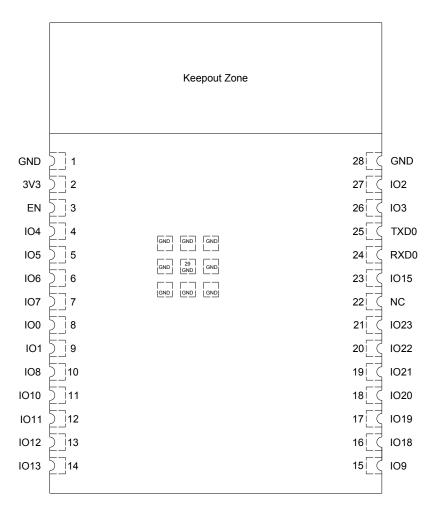


Figure 3: Pin Layout (Top View)

3.2 Pin Description

The module has 29 pins. See pin definitions in Table 3 Pin Definitions.

For peripheral pin configurations, please refer to *ESP32-C6 Series Datasheet*.

Table 3: Pin Definitions

Name	No.	Type ¹	Function
GND	1	Р	Ground

Table 3 - cont'd from previous page

	Table 5 – Cont d from previous page			
Name	No.	Type ¹	Function	
3V3	2	Р	Power supply	
EN	3		High: on, enables the chip.	
		'	Low: off, the chip powers off.	
			Note: Do not leave the EN pin floating.	
IO4	4	I/O/T	MTMS, GPIO4, LP_GPIO4, LP_UART_RXD, ADC1_CH4, FSPIHD	
IO5	5	I/O/T	MTDI, GPIO5, LP_GPIO5, LP_UART_TXD, ADC1_CH5, FSPIWP	
IO6	6	I/O/T	MTCK, GPIO6, LP_GPIO6, LP_I2C_SDA, ADC1_CH6, FSPICLK	
107	7	I/O/T	MTDO, GPIO7, LP_GPIO7, LP_I2C_SCL, FSPID	
100	8	I/O/T	GPIO0, XTAL_32K_P, LP_GPIO0, LP_UART_DTRN, ADC1_CH0	
IO1	9	I/O/T	GPIO1, XTAL_32K_N, LP_GPIO1, LP_UART_DSRN, ADC1_CH1	
IO8	10	I/O/T	GPIO8	
IO10	11	I/O/T	GPIO10	
IO11	12	I/O/T	GPIO11	
IO12	13	I/O/T	GPIO12, USB_D-	
IO13	14	I/O/T	GPIO13, USB_D+	
109	15	I/O/T	GPIO9	
IO18	16	I/O/T	GPIO18, SDIO_CMD, FSPICS2	
IO19	17	I/O/T	GPIO19, SDIO_CLK, FSPICS3	
IO20	18	I/O/T	GPIO20, SDIO_DATA0, FSPICS4	
IO21	19	I/O/T	GPIO21, SDIO_DATA1, FSPICS5	
IO22	20	I/O/T	GPIO22, SDIO_DATA2	
IO23	21	I/O/T	GPIO23, SDIO_DATA3	
NC	22	_	NC	
IO15	23	I/O/T	GPIO15	
RXD0	24	I/O/T	U0RXD, GPI017, FSPICS1	
TXD0	25	I/O/T	U0TXD, GPIO16, FSPICS0	
IO3	26	I/O/T	GPIO3, LP_GPIO3, LP_UART_CTSN, ADC1_CH3	
IO2	27	I/O/T	GPIO2, LP_GPIO2, LP_UART_RTSN, ADC1_CH2, FSPIQ	
GND	28	Р	Ground	
EPAD	29	Р	Ground	
			ı	

¹ P: power supply; I: input; O: output; T: high impedance.

3.3 Strapping Pins

Note:

The content below is excerpted from <u>ESP32-C6 Series Datasheet</u> > Section <u>Strapping Pins</u>. For the strapping pin mapping between the chip and modules, please refer to Chapter 6 <u>Module Schematics</u>.

At each startup or reset, a chip requires some initial configuration parameters, such as in which boot mode to load the chip, etc. These parameters are passed over via the strapping pins. After reset, the strapping pins operate as regular IO pins.

The parameters controlled by the given strapping pins at chip reset are as follows:

- SDIO sampling and driving clock edge MTMS and MTDI
- Chip boot mode GPIO8 and GPIO9
- ROM code printing to UART GPIO8
- JTAG signal source GPIO15

GPIO9 is connected to the chip's internal weak pull-up resistor at chip reset. This resistor determines the default bit value of GPIO9. Also, the resistor determines the bit value if GPIO9 is connected to an external high-impedance circuit.

Table 4: Default Configuration of Strapping Pins

Strapping Pin	Default Configuration	Bit Value
MTMS	Floating	_
MTDI	Floating	_
GPIO8	Floating	_
GPIO9	Pull-up	1
GPIO15	Floating	_

To change the bit values, the strapping pins should be connected to external pull-down/pull-up resistances. If the ESP32-C6 is used as a device by a host MCU, the strapping pin voltage levels can also be controlled by the host MCU.

All strapping pins have latches. At system reset, the latches sample the bit values of their respective strapping pins and store them until the chip is powered down or shut down. The states of latches cannot be changed in any other way. It makes the strapping pin values available during the entire chip operation, and the pins are freed up to be used as regular IO pins after reset.

Regarding the timing requirements for the strapping pins, there are such parameters as *setup time* and *hold time*. For more information, see Table 5 and Figure 4.

Table 5: Description of Timing Parameters for the Strapping Pins

Parameter	Description	Min (ms)
+	Setup time is the time reserved for the power rails to stabilize before	
t_{SU}	the CHIP_PU pin is pulled high to activate the chip.	0
	Hold time is the time reserved for the chip to read the strapping pin	
t_H	values after CHIP_PU is already high and before these pins start	3
	operating as regular IO pins.	

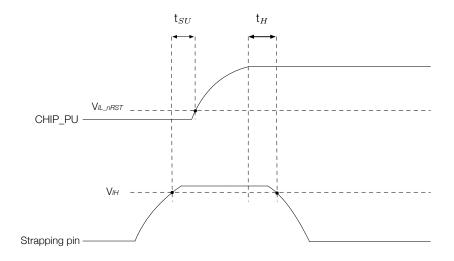


Figure 4: Visualization of Timing Parameters for the Strapping Pins

3.3.1 SDIO Sampling and Driving Clock Edge Control

The strapping pin MTMS and MTDI can be used to decide on which clock edge to sample signals and drive output lines. See Table 6 SDIO Input Sampling Edge/Output Driving Edge Control.

Table 6: SDIO Input Sampling Edge/Output Driving Edge Control

MTMS	MTDI	Edge behavior	
- (Floating)	- (Floating)	Default Configuration	
0	0	Falling edge sampling, falling edge output	
0	1	Falling edge sampling, rising edge output	
1	0	Rising edge sampling, falling edge output	
1	1	Rising edge sampling, rising edge output	

3.3.2 Chip Boot Mode Control

GPIO8 and GPIO9 control the boot mode after the reset is released. See Table 7 Boot Mode Control Boot Mode Control.

Table 7: Boot Mode Control

Boot Mode	GPIO8	GPIO9
Default Configuration	- (Floating)	1 (Pull-up)
SPI Boot (default)	Any value	1
Download Boot	1	0
Invalid combination ¹	0	0

¹ This combination triggers unexpected behavior and should be avoided.

3.3.3 ROM Messages Printing Control

During boot process the messages by the ROM code can be printed to:

- **USB Serial/JTAG controller**. For this, EFUSE_DIS_USB_SERIAL_JTAG_ROM_PRINT should be 0 and USB Serial/JTAG controller should be enabled.
- UARTO. For this, set EFUSE_DIS_USB_SERIAL_JTAG_ROM_PRINT to 1. In this case,
 EFUSE_UART_PRINT_CONTROL and GPIO8 control ROM messages printing as shown in Table 8 ROM Messages Printing Control.

Table 8: ROM Messages Printing Control

eFuse ¹	GPIO8	ROM Code Printing
0	Ignored	Always enabled
-1	0	Enabled
l l	1	Disabled
2	0	Disabled
	1	Enabled
3	Ignored	Always disabled

¹ eFuse: EFUSE_UART_PRINT_CONTROL

3.3.4 JTAG Signal Source Control

The strapping pin GPIO15 can be used to control the source of JTAG signals during the early boot process. This pin does not have any internal pull resistors and the strapping value must be controlled by the external circuit that cannot be in a high impedance state.

As Table 9 shows, GPIO15 is used in combination with EFUSE_DIS_PAD_JTAG, EFUSE_DIS_USB_JTAG, and EFUSE_JTAG_SEL_ENABLE.

Table 9: JTAG Signal Source Control

eFuse 1ª	eFuse 2 ^b	eFuse 3 ^c	GPIO15	JTAG Signal Source
		0	Ignored	USB Serial/JTAG Controller
0	0	4	0	JTAG pins MTDI, MTCK, MTMS, and MTDO
		ı ı	1	USB Serial/JTAG Controller
0	1	Ignored	Ignored	JTAG pins MTDI, MTCK, MTMS, and MTDO
1	0	Ignored	Ignored	USB Serial/JTAG Controller
1	1	Ignored	Ignored	JTAG is disabled

^a eFuse 1: EFUSE DIS PAD JTAG

^b eFuse 2: EFUSE_DIS_USB_JTAG

[°] eFuse 3: EFUSE_JTAG_SEL_ENABLE

Electrical Characteristics

The values presented in this section are preliminary and may change with the final release of this datasheet.

Absolute Maximum Ratings 4.1

Stresses above those listed in Table 10 Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under Table 11 Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Table 10: Absolute Maximum Ratings

Symbol	Parameter	Min	Max	Unit
VDD33	Power supply voltage	-0.3	3.6	V
T_{STORE}	Storage temperature	-40	105	°C

Recommended Operating Conditions

Table 11: Recommended Operating Conditions

Symbol	Parameter			Тур	Max	Unit
VDD33	Power supply voltage		3.0	3.3	3.6	V
$ V_{VDD} $	Current delivered by external power supply		0.5	_	_	Α
т	Operating embient temperature	85 °C version	-40		85	°C
	T _A Operating ambient temperature		-4 0		105	C

4.3 DC Characteristics (3.3 V, 25 °C)

Table 12: DC Characteristics (3.3 V, 25 °C)

Symbol	Parameter	Min	Тур	Max	Unit
C_{IN}	Pin capacitance	_	2	_	рF
V_{IH}	High-level input voltage	$0.75 \times VDD^1$	_	VDD ¹ + 0.3	V
V_{IL}	Low-level input voltage	-0.3	_	$0.25 \times VDD^1$	V
$ _{IH}$	High-level input current		_	50	nA
$ I_{IL} $	Low-level input current	_	_	50	nA
V_{OH}^2	High-level output voltage	$0.8 \times VDD^1$	_	_	V
V_{OL}^2	Low-level output voltage		_	$0.1 \times VDD^1$	V
	High-level source current (VDD 1 = 3.3 V, V $_{OH}$ >=		40		mA
$ I_{OH} $	2.64 V, PAD_DRIVER = 3)	_	40	_	IIIA
	Low-level sink current (VDD1 = 3.3 V, V_{OL} =		28		mA
$ I_{OL} $	0.495 V, PAD_DRIVER = 3)	_	20		IIIA
R_{PU}	Pull-up resistor	_	45	_	kΩ

R_{PD}	Pull-down resistor	_	45	_	kΩ
V_{IH_nRST}	Chip reset release voltage	$0.75 \times VDD^1$	_	VDD ¹ + 0.3	V
V_{IL_nRST}	Chip reset voltage	-0.3	_	$0.25 \times VDD^1$	V

¹ VDD is the I/O voltage for pins of a particular power domain.

Current Consumption Characteristics

4.4.1 **Current Consumption in Active Mode**

The current consumption measurements are taken with a 3.3 V supply at 25 °C ambient temperature.

TX current consumption is rated at a 100% duty cycle.

RX current consumption is rated when the peripherals are disabled and the CPU idle.

Table 13: Current Consumption for Wi-Fi (2.4 GHz) in Active Mode

Work Mode	RF Condition	Description	Peak (mA)
		802.11b, 1 Mbps, DSSS @ 20.5 dBm	382
		802.11g, 54 Mbps, OFDM @ 19.0 dBm	316
	TX	802.11n, HT20, MCS7 @ 18.0 dBm	295
Active (RF working)		802.11n, HT40, MCS7 @ 17.5 dBm	280
Active (11 Working)		802.11ax, MCS9 @ 15.5 dBm	251
		802.11b/g/n, HT20	78
	RX	802.11n, HT40	82
		802.11ax, HE20	78

Table 14: Current Consumption for Bluetooth LE in Active Mode

Work Mode	RF Condition	Description	Peak (mA)
		Bluetooth LE @ 20.0 dBm	322
	TX	Bluetooth LE @ 9.0 dBm	190
Active (RF working)		Bluetooth LE @ 0 dBm	130
		Bluetooth LE @ -24.0 dBm	90
	RX	Bluetooth LE	73

Table 15: Current Consumption for 802.15.4 in Active Mode

Work Mode	RF Condition	Description	Peak (mA)
		802.15.4 @ 20.0 dBm	316
	TX	802.15.4 @ 12.0 dBm	190
Active (RF working)		802.15.4 @ 0 dBm	120
		802.15.4 @ -24.0 dBm	84
	RX	802.15.4	73

 $^{^2\ {\}rm V}_{OH}$ and ${\rm V}_{OL}$ are measured using high-impedance load.

Note:

The content below is excerpted from Section Current Consumption in Other Modes in ESP32-C6 Series Datasheet.

4.4.2 Current Consumption in Other Modes

Table 16: Current Consumption in Modem-sleep Mode

	CPU Frequency		Typ (mA)		
Mode	(MHz)	Description	All Peripherals	All Peripherals	
Wiode	(1411 12)	Description	Clocks Disabled	Clocks Enabled ¹	
	160	CPU is running	27	38	
Modem-sleep ^{2,3}	100	CPU is idle	17	28	
Modern-Sieep	80	CPU is running	19	30	
	00	CPU is idle	14	25	

¹ In practice, the current consumption might be different depending on which peripherals are enabled.

Table 17: Current Consumption in Low-Power Modes

Mode	Description	Typ (μ A)	
	CPU and wireless communication modules are powered down, pe-	180	
Light-sleep	ripheral clocks are disabled, and all GPIOs are high-impedance	100	
	CPU, wireless communication modules and peripherals are pow-		
	ered down, and all GPIOs are high-impedance	35	
Deep-sleep	RTC timer and LP memory are powered on	7	
Power off	CHIP_PU is set to low level, the chip is powered off	1	

² In Modem-sleep mode, Wi-Fi is clock gated.

³ In Modem-sleep mode, the consumption might be higher when accessing flash.

RF Characteristics

This section contains tables with RF characteristics of the Espressif product.

The RF data is measured at the antenna port, where RF cable is connected, including the front-end loss. The external antennas used for the tests on the modules with external antenna connectors have an impedance of 50 Ω .

Devices should operate in the center frequency range allocated by regional regulatory authorities. The target center frequency range and the target transmit power are configurable by software. See ESP RF Test Tool and Test Guide for instructions.

Unless otherwise stated, the RF tests are conducted with a 3.3 V (±5%) supply at 25 °C ambient temperature.

Wi-Fi Radio (2.4 GHz/5 GHz) 5.1

Table 18: Wi-Fi RF Characteristics

Name	Description
Center frequency range of operating channel	2412 ~ 2484 MHz
Wi-Fi wireless standard	IEEE 802.11b/g/n/ax

5.1.1 Wi-Fi RF Transmitter (TX) Characteristics

Table 19: TX Power with Spectral Mask and EVM Meeting 802.11 Standards

	Min	Тур	Max
Rate	(dBm)	(dBm)	(dBm)
802.11b, 1 Mbps, DSSS	_	20.5	_
802.11b, 11 Mbps, CCK	_	20.5	_
802.11g, 6 Mbps, OFDM	_	20.0	_
802.11g, 54 Mbps, OFDM	_	19.0	_
802.11n, HT20, MCS0	_	19.0	_
802.11n, HT20, MCS7	_	18.0	_
802.11n, HT40, MCS0	_	18.5	_
802.11n, HT40, MCS7	_	17.5	_
802.11ax, HE20, MCS0	_	19.0	_
802.11ax, HE20, MCS9	_	15.5	_

Table 20: TX EVM Test1

Rate	Min (dB)	Typ (dB)	Limit (dB)
802.11b, 1 Mbps, DSSS	_	-25.0	-10.0
802.11b, 11 Mbps, CCK	_	-25.0	-10.0

Min Limit Тур Rate (dB) (dB) (dB) 802.11g, 6 Mbps, OFDM -24.0-5.0802.11g, 54 Mbps, OFDM -28.0-25.0 802.11n, HT20, MCS0 -27.5-5.0802.11n, HT20, MCS7 -27.0 -30.0802.11n, HT40, MCS0 -27.0-5.0-27.0 802.11n, HT40, MCS7 -29.5-27.0 802.11ax, HE20, MCS0 -5.0 802.11ax, HE20, MCS9 -34.0-32.0

Table 20 - cont'd from previous page

5.1.2 Wi-Fi RF Receiver (RX) Characteristics

For RX tests, the PER (packet error rate) limit is 8% for 802.11b, and 10% for 802.11g/n/ax.

Table 21: RX Sensitivity

	Min	Тур	Max
Rate	(dBm)	(dBm)	(dBm)
802.11b, 1 Mbps, DSSS	_	-99.2	_
802.11b, 2 Mbps, DSSS	_	-96.8	_
802.11b, 5.5 Mbps, CCK	_	-93.6	_
802.11b, 11 Mbps, CCK	_	-90.0	_
802.11g, 6 Mbps, OFDM	_	-94.0	_
802.11g, 9 Mbps, OFDM	_	-93.0	_
802.11g, 12 Mbps, OFDM	_	-92.4	_
802.11g, 18 Mbps, OFDM	_	-90.0	_
802.11g, 24 Mbps, OFDM	_	-86.8	_
802.11g, 36 Mbps, OFDM	_	-83.0	_
802.11g, 48 Mbps, OFDM	_	-78.8	_
802.11g, 54 Mbps, OFDM	_	-77.6	_
802.11n, HT20, MCS0	_	-93.6	_
802.11n, HT20, MCS1	_	-92.0	_
802.11n, HT20, MCS2	_	-89.4	_
802.11n, HT20, MCS3	_	-86.0	_
802.11n, HT20, MCS4	_	-82.8	_
802.11n, HT20, MCS5	_	-78.6	_
802.11n, HT20, MCS6	_	-77.0	_
802.11n, HT20, MCS7	_	-75.4	_
802.11n, HT40, MCS0	_	-91.0	
802.11n, HT40, MCS1	_	-89.6	_
		t'd on no	

¹ EVM is measured at the corresponding typical TX power provided in Table 19 TX Power with Spectral Mask and EVM Meeting 802.11 Standards above.

Table 21 - cont'd from previous page

	Min	Тур	Max
Rate	(dBm)	(dBm)	(dBm)
802.11n, HT40, MCS2		-87.0	
802.11n, HT40, MCS3		-83.4	_
802.11n, HT40, MCS4	_	-80.4	
802.11n, HT40, MCS5		-76.2	_
802.11n, HT40, MCS6	_	-74.6	
802.11n, HT40, MCS7	_	-73.2	_
802.11ax, HE20, MCS0	_	-93.8	
802.11ax, HE20, MCS1		-91.0	_
802.11ax, HE20, MCS2	_	-88.0	
802.11ax, HE20, MCS3	_	-85.6	_
802.11ax, HE20, MCS4	_	-82.0	
802.11ax, HE20, MCS5	_	-78.0	
802.11ax, HE20, MCS6	_	-76.6	
802.11ax, HE20, MCS7	_	-74.4	_
802.11ax, HE20, MCS8	_	-70.8	_
802.11ax, HE20, MCS9	_	-68.6	_

Table 22: Maximum RX Level

	Min	Тур	Max
Rate	(dBm)	(dBm)	(dBm)
802.11b, 1 Mbps, DSSS	_	5	_
802.11b, 11 Mbps, CCK	_	5	_
802.11g, 6 Mbps, OFDM	_	5	_
802.11g, 54 Mbps, OFDM	_	0	_
802.11n, HT20, MCS0	_	5	_
802.11n, HT20, MCS7	_	0	_
802.11n, HT40, MCS0	_	5	_
802.11n, HT40, MCS7	_	0	_
802.11ax, HE20, MCS0	_	5	_
802.11ax, HE20, MCS9	_	0	_

Table 23: RX Adjacent Channel Rejection

	Min	Тур	Max
Rate	(dB)	(dB)	(dB)
802.11b, 1 Mbps, DSSS	_	38	_
802.11b, 11 Mbps, CCK	_	38	_
802.11g, 6 Mbps, OFDM	_	31	_
802.11g, 54 Mbps, OFDM	_	20	

Table 23 - cont'd from previous page

	Min	Тур	Max
Rate	(dB)	(dB)	(dB)
802.11n, HT20, MCS0	_	31	_
802.11n, HT20, MCS7	_	16	
802.11n, HT40, MCS0	_	28	_
802.11n, HT40, MCS7	_	10	_
802.11ax, HE20, MCS0	_	25	
802.11ax, HE20, MCS9		2	_

5.2 Bluetooth 5 (LE) Radio

Table 24: Bluetooth LE RF Characteristics

Name	Description
Center frequency range of operating channel	2402 ~ 2480 MHz
RF transmit power range	−24.0 ~ 20.0 dBm

5.2.1 Bluetooth LE RF Transmitter (TX) Characteristics

Table 25: Bluetooth LE - Transmitter Characteristics - 1 Mbps

Parameter	Description	Min	Тур	Max	Unit
	Max. $ f_n _{n=0, 1, 2, 3,k}$		1.3	_	kHz
Carrier frequency offset and drift	Max. $ f_0 - f_n _{n=2, 3, 4,k}$	_	1.5	_	kHz
Carrier frequency offset and drift	Max. $ f_{n-1} _{n=6, 7, 8,k}$		0.9	_	kHz
	$ f_1 - f_0 $		0.6	_	kHz
	$\Delta F1_{avg}$		249.9	_	kHz
Modulation characteristics	Min. Δ $F2_{\text{max}}$ (for at least		- 212.1		kHz
	99.9% of all Δ $F2_{\text{max}}$)			_	KI IZ
	$\Delta~F2_{ m avg}/\Delta~F1_{ m avg}$		0.88	_	
In-band emissions	± 2 MHz offset		-29	_	dBm
	± 3 MHz offset		-36	_	dBm
	> ± 3 MHz offset		-39	_	dBm

Table 26: Bluetooth LE - Transmitter Characteristics - 2 Mbps

Parameter	Description	Min	Тур	Max	Unit
Carrier frequency offset and drift	Max. $ f_n _{n=0, 1, 2, 3,k}$		2.2	_	kHz
	Max. $ f_0 - f_n _{n=2, 3, 4,k}$		1.1	_	kHz
	Max. $ f_{n-1} _{n=6, 7, 8,k}$		1.1	_	kHz
	$ f_1 - f_0 $		0.5	_	kHz
	$\Delta F1_{ ext{avg}}$	_	499.4	_	kHz

Modulation characteristics

Table 26 - cont'd from previous page

Parameter	Description	Min	Тур	Max	Unit
	Min. Δ $F2_{\text{max}}$ (for at least		443.5		kHz
	99.9% of all Δ $F2_{\text{max}}$)		443.5		NI IZ
	$\Delta F2_{\text{avg}}/\Delta F1_{\text{avg}}$	_	0.95		_
	± 4 MHz offset	_	-40	_	dBm
In-band emissions	± 5 MHz offset	_	-41	_	dBm
	> ± 5 MHz offset	_	-42	_	dBm

Table 27: Bluetooth LE - Transmitter Characteristics - 125 Kbps

Parameter	Description	Min	Тур	Max	Unit
	Max. $ f_n _{n=0, 1, 2, 3,k}$	_	0.7	_	kHz
Carrier frequency offset and drift	Max. $ f_0 - f_n _{n=1, 2, 3,k}$	_	0.3		kHz
	$ f_0 - f_3 $		0.1	_	kHz
	Max. $ f_{n-1}f_{n-3} _{n=7, 8, 9,k}$	_	0.4		kHz
Modulation characteristics	$\DeltaF1_{ m avg}$		250.0		kHz
IVIOUIIALION CHARACTERISTICS	Min. Δ $F1_{\text{max}}$ (for at least		238.0		kHz
	99.9% of all Δ $F1_{\rm max}$)		230.0		KI IZ
	± 2 MHz offset		-29	_	dBm
In-band emissions	± 3 MHz offset		-36	_	dBm
	> ± 3 MHz offset		-39		dBm

Table 28: Bluetooth LE - Transmitter Characteristics - 500 Kbps

Parameter	Description	Min	Тур	Max	Unit
	Max. $ f_n _{n=0, 1, 2, 3,k}$	_	0.5	_	kHz
Carrier frequency offset and drift	Max. $ f_0 - f_n _{n=1, 2, 3,k}$	_	0.3	_	kHz
Carrier frequency offset and drift	$ f_0 - f_3 $	_	0.1	_	kHz
	Max. $ f_{n-1}f_{n-3} _{n=7, 8, 9,k}$		0.4		kHz
Modulation characteristics	$\Delta~F2_{ m avg}$	_	230.7	_	kHz
IVIOUUIALION CHARACTERISTICS	Min. Δ $F2_{\rm max}$ (for at least		217.6		kHz
	99.9% of all Δ $F2_{\text{max}}$)	_	217.0	_	NITZ
	± 2 MHz offset	_	-28		dBm
In-band emissions	± 3 MHz offset	_	-36	_	dBm
	> ± 3 MHz offset	_	-39	_	dBm

5.2.2 Bluetooth LE RF Receiver (RX) Characteristics

Table 29: Bluetooth LE - Receiver Characteristics - 1 Mbps

Parameter	Description	Min	Тур	Max	Unit
Sensitivity @30.8% PER	_	_	-98.0	_	dBm
Maximum received signal @30.8% PER	_	_	8	_	dBm

Table 29 - cont'd from previous page

Parameter		Description	Min	Тур	Max	Unit
	Co-channel	F = F0 MHz	_	7	_	dB
		F = F0 + 1 MHz	_	4	_	dB
		F = F0 - 1 MHz	_	3	_	dB
		F = F0 + 2 MHz	_	-21	_	dB
	Adjacent channel	F = F0 - 2 MHz	_	-22	_	dB
C/I and receiver	Aujacent Channel	F = F0 + 3 MHz	_	-28	_	dB
selectivity performance		F = F0 - 3 MHz	_	-36	_	dB
		$F \ge F0 + 4 MHz$	_	-27	_	dB
		$F \le F0 - 4 MHz$	_	-36	_	dB
	Image frequency	_	_	-26	_	dB
	Adjacent channel to	$F = F_{image} + 1 \text{ MHz}$	_	-29	_	dB
	image frequency	$F = F_{image} - 1 \text{ MHz}$	_	-28	_	dB
		30 MHz ~ 2000 MHz	_	-16	_	dBm
Out-of-band blocking performance		2003 MHz ~ 2399 MHz	_	-24	_	dBm
		2484 MHz ~ 2997 MHz	_	-16	_	dBm
		3000 MHz ~ 12.75 GHz	_	-1	_	dBm
Intermodulation		_	_	-27		dBm

Table 30: Bluetooth LE - Receiver Characteristics - 2 Mbps

Parameter		Description	Min	Тур	Max	Unit
Sensitivity @30.8% PER		_	_	-95.0	_	dBm
Maximum received signa	al @30.8% PER	_	_	8		dBm
	Co-channel	F = F0 MHz	_	8	_	dB
		F = F0 + 2 MHz	_	3	_	dB
		F = F0 - 2 MHz	_	2	_	dB
		F = F0 + 4 MHz	_	-23	_	dB
	Adjacent channel	F = F0 - 4 MHz	_	-25	_	dB
C/I and receiver selectivity performance		F = F0 + 6 MHz	_	-31	_	dB
		F = F0 - 6 MHz	_	-35	_	dB
		$F \ge F0 + 8 MHz$	_	-36	_	dB
		$F \le F0 - 8 MHz$	_	-36	_	dB
	Image frequency	_	_	-23	_	dB
	Adjacent channel to	$F = F_{image} + 2 MHz$		-30	_	dB
	image frequency	$F = F_{image} - 2 \text{ MHz}$	_	3	_	dB
				-18	_	dBm
Out-of-band blocking performance		2003 MHz ~ 2399 MHz	_	-28	_	dBm
		2484 MHz ~ 2997 MHz	_	-16	_	dBm
		3000 MHz ~ 12.75 GHz	_	-1	_	dBm
Intermodulation		_		-29	_	dBm

Table 31: Bluetooth LE - Receiver Characteristics - 125 Kbps

Parameter		Description	Min	Тур	Max	Unit
Sensitivity @30.8% PER		_	_	-105.5	_	dBm
Maximum received signa	al @30.8% PER	_	_	8	_	dBm
	Co-channel	F = F0 MHz	_	2	_	dB
		F = F0 + 1 MHz	_	-1	_	dB
	Adjacent channel	F = F0 – 1 MHz	_	-3	_	dB
		F = F0 + 2 MHz	_	-31	_	dB
		F = F0 – 2 MHz	_	-27	_	dB
C/I and receiver	Adjacent channel	F = F0 + 3 MHz	_	-33	_	dB
selectivity performance		F = F0 – 3 MHz	_	-42	_	dB
		F ≥ F0 + 4 MHz		-31	_	dB
		$F \le F0 - 4 \text{ MHz}$	_	-48	_	dB
	Image frequency	_		-31	_	dB
	Adjacent channel to	$F = F_{image} + 1 \text{ MHz}$	_	-36	_	dB
	image frequency	$F = F_{image} - 1 \text{ MHz}$	_	-33		dB

Table 32: Bluetooth LE - Receiver Characteristics - 500 Kbps

Parameter		Description	Min	Тур	Max	Unit
Sensitivity @30.8% PER		_	_	-101.5	_	dBm
Maximum received signa	al @30.8% PER	_	_	8	_	dBm
	Co-channel	F = F0 MHz	_	4	_	dB
		F = F0 + 1 MHz	_	1	_	dB
	Adjacent channel	F = F0 – 1 MHz	_	-1	_	dB
		F = F0 + 2 MHz	_	-23	_	dB
		F = F0 – 2 MHz	_	-24	_	dB
C/I and receiver		F = F0 + 3 MHz	_	-33	_	dB
selectivity performance		F = F0 - 3 MHz	_	-41	_	dB
		$F \ge F0 + 4 MHz$	_	-31	_	dB
		$F \le F0 - 4 \text{ MHz}$	_	-41	_	dB
	Image frequency	_		-30	_	dB
	Adjacent channel to	$F = F_{image} + 1 \text{ MHz}$	_	-35	_	dB
	image frequency	$F = F_{image} - 1 \text{ MHz}$	_	-27	_	dB

5.3 802.15.4 Radio

Table 33: 802.15.4 RF Characteristics

Name	Description
Center frequency range of operating channel	2405 ~ 2480 MHz

¹ Zigbee in the 2.4 GHz range supports 16 channels at 5 MHz spacing from channel 11 to channel 26.

5.3.1 802.15.4 RF Transmitter (TX) Characteristics

Table 34: 802.15.4 Transmitter Characteristics - 250 Kbps

Parameter	Min	Тур	Max	Unit
RF transmit power range	-24.0	_	20.0	dBm
EVM	_	13%	_	_

5.3.2 802.15.4 RF Receiver (RX) Characteristics

Table 35: 802.15.4 Receiver Characteristics - 250 Kbps

Parameter		Description	Min	Тур	Max	Unit
Sensitivity @1% PER		_	_	-104.0	_	dBm
Maximum received signal @1% PER		_	_	8		dBm
	Adjacent channel elative jamming level Alternate channel	F = F0 + 5 MHz	_	27	_	dB
Polativa iamming laval		F = F0 - 5 MHz	_	32	_	dB
helative jarriming level		F = F0 + 10 MHz		47	_	dB
		F = F0 - 10 MHz	_	50		dB

0

6 Module Schematics

This is the reference design of the module.

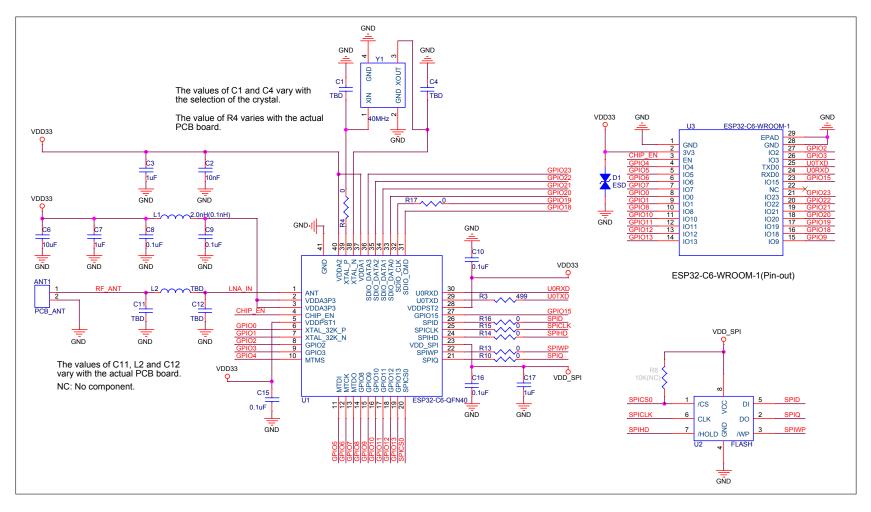


Figure 5: ESP32-C6-WROOM-1 Schematics

0

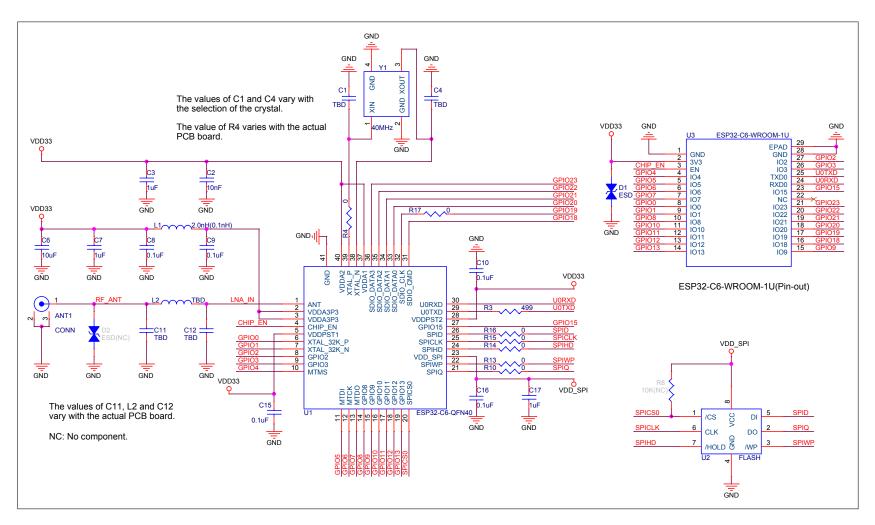


Figure 6: ESP32-C6-WROOM-1U Schematics

7 Peripheral Schematics

This is the typical application circuit of the module connected with peripheral components (for example, power supply, antenna, reset button, JTAG interface, and UART interface).

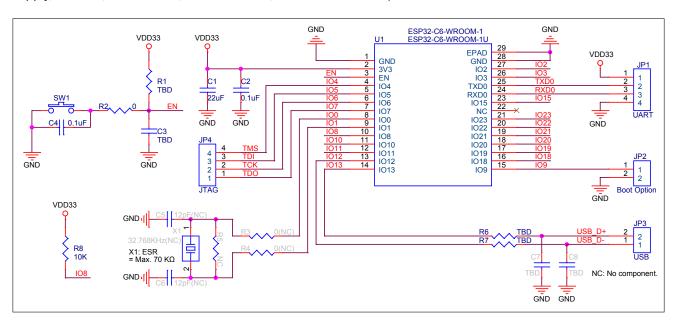


Figure 7: Peripheral Schematics

- Soldering the EPAD to the ground of the base board is not a must, however, it can optimize thermal
 performance. If you choose to solder it, please apply the correct amount of soldering paste. Too much
 soldering paste may increase the gap between the module and the baseboard. As a result, the adhesion
 between other pins and the baseboard may be poor.
- To ensure that the power supply to the ESP32-C6 chip is stable during power-up, it is advised to add an RC delay circuit at the EN pin. The recommended setting for the RC delay circuit is usually R = 10 kΩ and C = 1 μF. However, specific parameters should be adjusted based on the power-up timing of the module and the power-up and reset sequence timing of the chip. For ESP32-C6's power-up and reset sequence timing diagram, please refer to ESP32-C6 Series Datasheet > Section Power Supply.

8 Physical Dimensions and PCB Land Pattern

8.1 Physical Dimensions

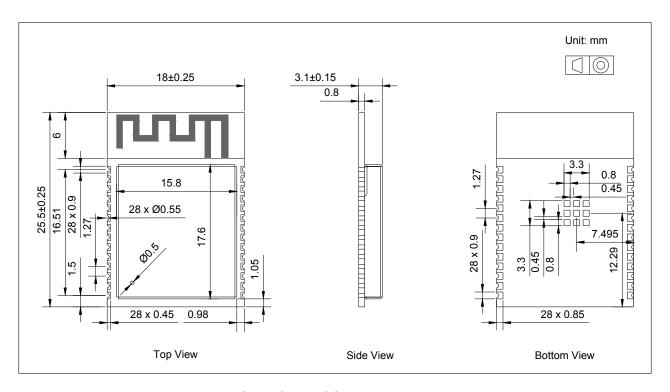


Figure 8: ESP32-C6-WROOM-1 Physical Dimensions

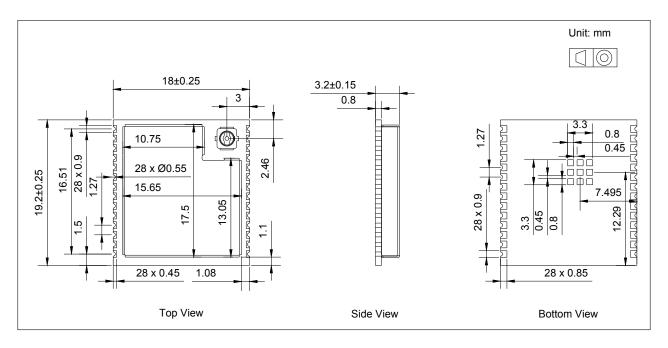


Figure 9: ESP32-C6-WROOM-1U Physical Dimensions

Note:

For information about tape, reel, and product marking, please refer to Espressif Module Packaging Information.

8.2 Recommended PCB Land Pattern

This section provides the following resources for your reference:

- Figures for recommended PCB land patterns with all the dimensions needed for PCB design. See Figure 10 ESP32-C6-WROOM-1 Recommended PCB Land Pattern and Figure 11 ESP32-C6-WROOM-1U Recommended PCB Land Pattern.
- Source files of recommended PCB land patterns to measure dimensions not covered in Figure 10. You can view the source files for ESP32-C6-WROOM-1 with Autodesk Viewer.

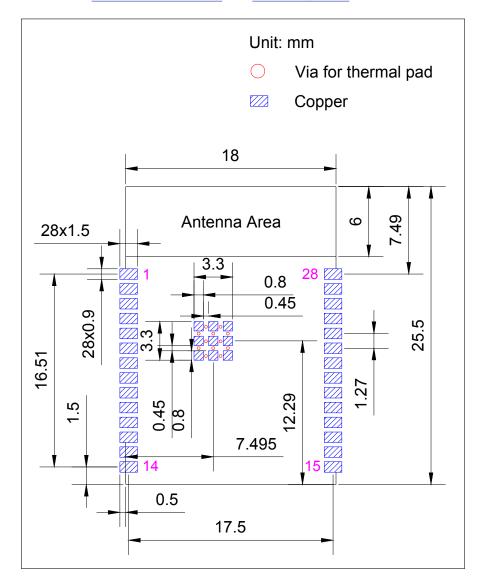


Figure 10: ESP32-C6-WROOM-1 Recommended PCB Land Pattern

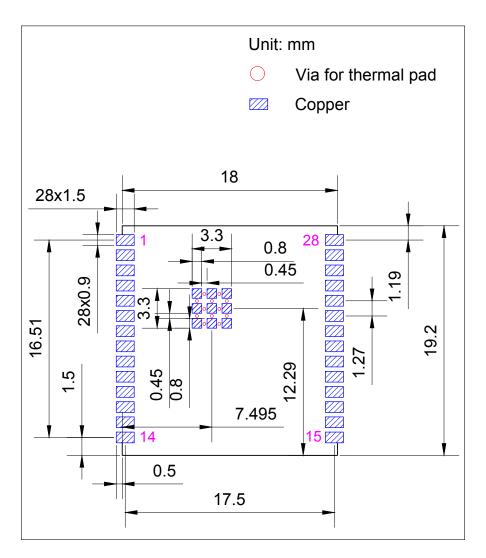


Figure 11: ESP32-C6-WROOM-1U Recommended PCB Land Pattern

8.3 **Dimensions of External Antenna Connector**

ESP32-C6-WROOM-1U uses the first generation external antenna connector as shown in Figure 12 Dimensions of External Antenna Connector. This connector is compatible with the following connectors:

- U.FL Series connector from Hirose
- MHF I connector from I-PEX
- AMC connector from Amphenol

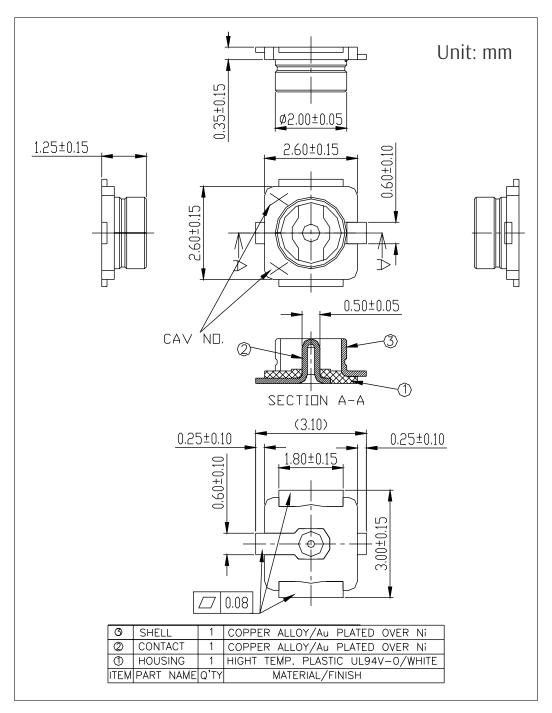


Figure 12: Dimensions of External Antenna Connector

9 Product Handling

9.1 Storage Conditions

The products sealed in moisture barrier bags (MBB) should be stored in a non-condensing atmospheric environment of < 40 °C and 90%RH. The module is rated at the moisture sensitivity level (MSL) of 3.

After unpacking, the module must be soldered within 168 hours with the factory conditions 25±5 °C and 60%RH. If the above conditions are not met, the module needs to be baked.

9.2 Electrostatic Discharge (ESD)

Human body model (HBM): ±2000 V
 Charged-device model (CDM): ±500 V

9.3 Soldering Profile

9.3.1 Reflow Profile

Solder the module in a single reflow.

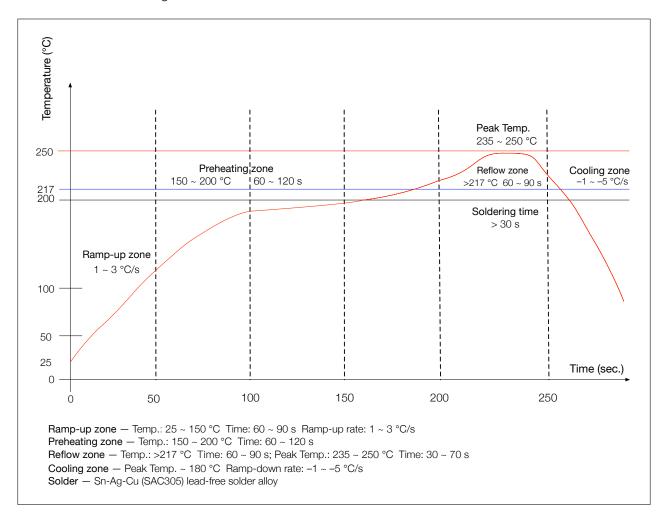


Figure 13: Reflow Profile

Ultrasonic Vibration 9.4

Avoid exposing Espressif modules to vibration from ultrasonic equipment, such as ultrasonic welders or ultrasonic cleaners. This vibration may induce resonance in the in-module crystal and lead to its malfunction or even failure. As a consequence, the module may stop working or its performance may deteriorate.

Related Documentation and Resources

Related Documentation

- ESP32-C6 Series Datasheet Specifications of the ESP32-C6 hardware.
- ESP32-C6 Technical Reference Manual Detailed information on how to use the ESP32-C6 memory and peripherals.
- ESP32-C6 Hardware Design Guidelines Guidelines on how to integrate the ESP32-C6 into your hardware product.
- Certificates

https://espressif.com/en/support/documents/certificates

• Documentation Updates and Update Notification Subscription https://espressif.com/en/support/download/documents

Developer Zone

• ESP-IDF and other development frameworks on GitHub.

https://github.com/espressif

 ESP32 BBS Forum – Engineer-to-Engineer (E2E) Community for Espressif products where you can post questions, share knowledge, explore ideas, and help solve problems with fellow engineers.

https://esp32.com/

• The ESP Journal - Best Practices, Articles, and Notes from Espressif folks.

https://blog.espressif.com/

• See the tabs SDKs and Demos, Apps, Tools, AT Firmware. https://espressif.com/en/support/download/sdks-demos

Products

• ESP32-C6 Series SoCs – Browse through all ESP32-C6 SoCs.

https://espressif.com/en/products/socs?id=ESP32-C6

• ESP32-C6 Series Modules - Browse through all ESP32-C6-based modules.

https://espressif.com/en/products/modules?id=ESP32-C6

• ESP32-C6 Series DevKits - Browse through all ESP32-C6-based devkits.

https://espressif.com/en/products/devkits?id=ESP32-C6

• ESP Product Selector - Find an Espressif hardware product suitable for your needs by comparing or applying filters. https://products.espressif.com/#/product-selector?language=en

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• See the tabs Sales Questions, Technical Enquiries, Circuit Schematic & PCB Design Review, Get Samples (Online stores), Become Our Supplier, Comments & Suggestions.

https://espressif.com/en/contact-us/sales-questions

Revision History

Date	Version	Release notes
2023-04-17	v0.6	Added information about ESP32-C6-WROOM-1U module
2023-02-16	v0.5	Preliminary release



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